
	<p>SI1970DH-T1-GE3</p>
	<p>Hersteller-Teilenummer: SI1970DH-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET 2N-CH 30V 1.3A SC70-6</p> <p>Datenblätter:  SI1970DH-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3250 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1970DH-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 30V 1.3A SC70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	3250 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.25W
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.3A
Rds On (Max) @ Id, Vgs	225 mOhm @ 1.2A, 4.5V
VGS (th) (Max) @ Id	1.6V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	3.8nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	95pF @ 15V
Verpackung	Tape & Reel (TR)
































SI1970DH-T1-GE3 ist neu im Original, Suche SI1970DH-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1970DH-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1970DH-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1972DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 1.3A SC70-6</p>	 <p>SI1969DH-E3 VISHAY SI1969DH-E3 VISHAY</p>	 <p>SI1967DH-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 20V 1.3A SC70-6</p>	 <p>SI1970DH-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 1.3A SC70-6</p>
 <p>SI1972DH-T1-E3 Vishay / Siliconix MOSFET 2N-CH 30V 1.3A SC70-6</p>	 <p>SI1970DH-T1-E3 Vishay / Siliconix MOSFET 2N-CH 30V 1.3A SC70-6</p>	 <p>SI1967DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 20V 1.3A SC70-6</p>	 <p>SI1970DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 1.3A SC70-6</p>

heiße Teile

Mehr

 SI1905DL-T1	 SI1905DL-T1-E3	 SI1905DL-T1-GE3	 SI1905DL-T1-GE3	 SI1906DL-T1
 SI1912EDH	 SI1912EDH-T1	 SI1912EDH-T1-E3	 SI1912EDH-T1-GE3	 SI1912EDH-T1-GE3
 SI1913DH-T1-E3	 SI1913DH-T1-E3	 SI1913DH-T1-GE3	 SI1913EDH-T1	 SI1913EDH-T1-E3
 SI1913EDH-T1-E3	 SI1913EDH-T1-GE3	 SI1917EDH-T1	 SI1917EDH-T1-E3	 SI1917EDH-T1-E3
 SI1917EDH-T1-GE3	 SI1922EDH-T1-GE3	 SI1922EDH-T1-GE3	 SI1926DL-T1-E3	 SI1926DL-T1-E3
 SI1926DL-T1-GE3	 SI1926DL-T1-GE3	 SI1958DH-T1-E3	 SI1958DH-T1-E3	 SI1965DH-E3
 SI1965DH-T1-E3	 SI1965DH-T1-E3	 SI1965DH-T1-GE3	 SI1965DH-T1-GE3	 SI1967DH-T1-E3
 SI1967DH-T1-E3	 SI1967DH-T1-GE3	 SI1967DH-T1-GE3	 SI1969DH-E3	 SI1970DH-T1-GE3
 SI1972DH-T1	 SI1972DH-T1-E3	 SI1972DH-T1-E3	 SI1972DH-T1-GE	 SI1972DH-T1-GE3
 SI1972DH-T1-GE3	 SI1973DH-E3	 SI1983DT-285-T1-E3	 SI1988DH-T1-GE3	 SI1988DH-T1-GE3

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